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# Two-dimensional graphitic carbon nitride/N-doped carbon with a direct Z-scheme heterojunction for photocatalytic generation of hydrogen†

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Photocatalysts with a direct Z-scheme heterojunction are promising by virtue of the effectively enhanced separation of charge carriers, high retention of redox ability and the absence of backward photocatalytic reactions. Their activity depends on band alignment and interfacial configurations between two semiconductors for charge carrier kinetics and the effective active sites for photochemical reactions. Herein, a two-dimensional (2D) graphitic carbon nitride/Ndoped carbon (C<sub>3</sub>N<sub>4</sub>/NC) photocatalyst is synthesized by a gas template (NH<sub>4</sub>Cl)-assisted thermal condensation method. C<sub>3</sub>N<sub>4</sub>/NC has the synthetic merits of a direct Z-scheme heterojunction, 2D-2D interfacial contact, and enhanced specific surface area to improve charge separation kinetics and provide abundant active sites for photochemical reaction. It exhibits an over 46-fold increase of the photocatalytic hydrogen production rate compared to bulk C<sub>3</sub>N<sub>4</sub> under visible light illumination. This work demonstrates the great potential of 2D Z-scheme heterojunctions for photocatalysis and will inspire more related work in the future.

To effectively address sustainable energy and environmental issues, the conversion from solar energy to hydrogen production is regarded as a promising and pollution-free approach, which is achieved by photocatalytic technology.<sup>1-5</sup> Since the pioneering discovery of water splitting by Fujishima in 1972, numerous semiconductors (*e.g.*, TiO<sub>2</sub>, α-Fe<sub>2</sub>O<sub>3</sub>, CdS, Cu<sub>2</sub>O, and BiVO<sub>4</sub>) have been widely studied in photocatalysis.<sup>6-9</sup> However, challenges still exist in improving the separation rate of photogenerated electron–hole pairs in photocatalysts to enhance

the activity of water splitting.<sup>10,11</sup> To overcome these drawbacks, the heterojunction strategy has been employed as a practical approach for improving charge carrier separation efficiency and photocatalytic activity.<sup>12,13</sup>

According to the band alignment of two semiconductors, there are three types of heterojunctions (Fig. 1): type I (straddling gap), type II (staggered gap), and type III (broken gap). 14,15 Both electrons and holes are predominantly transferred on the surface of photocatalyst II in the type I heterojunction, which is not suitable for charge carrier separation; it is energetically unfavorable for charge carrier transfer in the type III heterojunction. For the type II heterojunction, the photogenerated electrons easily transfer from the high conduction band (CB) to low CB, while the holes transfer from the low valence band (VB) to high VB, which can promote the spatial separation of charge carriers and then improve the photocatalytic performance.14 However, two semiconductors with a similar staggered gap might present different processes of photoinduced charge carrier transfer, which resembles the letter "Z" and is defined as a Z-scheme heterojunction.16,17 As described in Fig. 1a-c, depending on the involvement of electron mediators, a Z-scheme heterojunction can be classified as traditional Z-scheme (redox-pair mediator),16 all-solid-state Z-scheme (solid mediator),18 and direct Z-scheme (no mediator).12 It should be noted that a direct Z-scheme heterojunction can avoid the selection and shielding effect of electron mediators as well as the backward photochemical reactions. Furthermore, the unique "Z" shape transport pathway of charge carriers (Fig. 1c, red box) allows the electrons with lower reduction ability preferentially recombine with the holes with lower oxidation ability, while the electrons with higher reduction ability and holes with higher oxidation ability remain in their corresponding CB and VB.19,20 Therefore, a direct Z-scheme heterojunction is highly desired for efficient photocatalysis since it provides a promising pathway for improving charge carrier transfer kinetics, highly preserving redox ability, and avoiding the backward photocatalytic reactions.

The selection of suitable semiconductors is a prerequisite for constructing a practical direct Z-scheme heterojunction.<sup>21</sup> To

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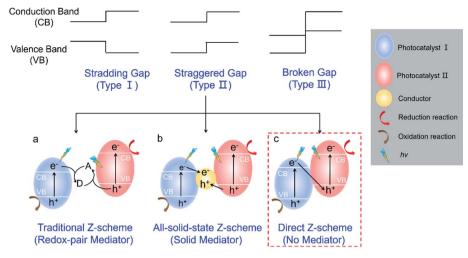


Fig. 1 Schematic illustration of different heterojunctions. (a) Traditional Z-scheme; (b) all-solid-state Z-scheme; (c) direct Z-scheme.

date, metal-based semiconductors are widely studied for H<sub>2</sub> production.1 However, severe metal leaching in metal-based photocatalysts will cause detrimental environmental pollution and thus greatly limit their large-scale applications. Therefore, the investigations of metal-free photocatalysts have received increasing attention.22 Graphitic carbon nitride (C3N4) as a promising metal-free photocatalyst shows great potential for photocatalytic H<sub>2</sub> generation, which is attributed to the 2D structure, suitable bandgap, high stability, tunable structure, and low cost. 23-26 However, the pure/bulk C<sub>3</sub>N<sub>4</sub> suffers from a slow rate of photoinduced charge carrier separation.27 The heterojunction strategy, pairing C<sub>3</sub>N<sub>4</sub> with a proper semiconductor, can be utilized to overcome the above mentioned disadvantages.<sup>28,29</sup> Yet the performance improvement is achieved at the expense of environmental pollution caused by metal leaching. N-doped carbon (NC), a metal-free material, is a promising coupling component for 2D heterojunctions due to its intrinsic characteristics of excellent electrical conductivity, a tunable band, and a matchable 2D structure with C<sub>3</sub>N<sub>4</sub>.30-33 Furthermore, the  $\pi$ - $\pi$  stacking interaction between C<sub>3</sub>N<sub>4</sub> and NC will enhance the charge carrier separation at the interface.34 Therefore, the construction of 2D C<sub>3</sub>N<sub>4</sub>/NC photocatalysts with a direct Z-scheme heterojunction is highly desired yet challenging, and it is also necessary to fully explore and understand the corresponding mechanism.

In the presented work, the 2D direct Z-scheme C<sub>3</sub>N<sub>4</sub>/NC photocatalysts exhibit remarkably enhanced photocatalytic activity. The manipulation of a direct Z-scheme heterojunction is achieved through the suitable staggered band structure and the  $\pi$ - $\pi$  stacking interaction between  $C_3N_4$  and NC, which endows C<sub>3</sub>N<sub>4</sub>/NC with a higher charge carrier separation rate and stronger redox ability. Besides, the 2D-2D structure of C<sub>3</sub>N<sub>4</sub>/NC results in a high specific surface area and large interfacial contact, which promotes fast charge carrier transfer and redox reactions. As a result, the synthesized 2D direct Z-scheme C<sub>3</sub>N<sub>4</sub>/NC photocatalysts show a remarkably enhanced visiblelight-driven  $H_2$  evolution rate of 3.060 mmol  $h^{-1}$   $g^{-1}$ , which is over 46 times that of bulk C<sub>3</sub>N<sub>4</sub>. The fundamental mechanism

of improved photocatalytic activity is also discussed in detail. This work may provide new perspectives on the rational design of 2D heterojunction materials with a direct Z-scheme mechanism.

The general fabrication process of C<sub>3</sub>N<sub>4</sub>/NC photocatalysts is illustrated in Fig. 2a, and the preparation details are provided in the experimental section. First, NC was prepared via a facile hydrothermal method, and bulk C<sub>3</sub>N<sub>4</sub> was synthesized through the polymerization of melamine. Then, C<sub>3</sub>N<sub>4</sub>/NC photocatalysts were obtained by calcining a mixture of NC, bulk C<sub>3</sub>N<sub>4</sub>, and NH<sub>4</sub>Cl. During the annealing process, NH<sub>4</sub>Cl as a gas template will be decomposed and release NH3 and HCl. These released gases can drive the formation of pores and exfoliate the stacked sheets of the bulk carbon nitride simultaneously.35 By regulating the mass ratio of NC in C<sub>3</sub>N<sub>4</sub>/NC, three different samples of C<sub>3</sub>N<sub>4</sub>/NC-I, C<sub>3</sub>N<sub>4</sub>/NC-II, and C<sub>3</sub>N<sub>4</sub>/NC-III were prepared with

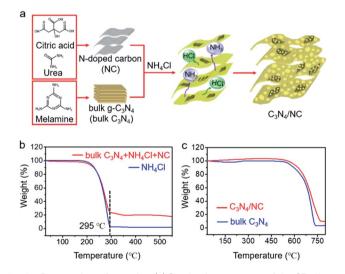


Fig. 2 Preparation of samples. (a) Synthesis processes of the 2D direct Z-scheme  $C_3N_4/NC$  photocatalysts; (b) thermogravimetric results of bulk  $C_3N_4 + NH_4Cl + NC$ , and  $NH_4Cl$ ; (c) thermogravimetric results of  $C_3N_4/NC$  and bulk  $C_3N_4$ .

the corresponding mass ratios of 0.05%, 0.075%, and 0.10%. The optimal  $C_3N_4/NC$ -II exhibits the best photocatalytic performance and is denoted as  $C_3N_4/NC$  unless otherwise stated. To understand the formation mechanism of  $C_3N_4/NC$ , thermogravimetric (TG) analysis was carried out. As presented in Fig. 2b, the NH $_4$ Cl gas template in the mixture of bulk  $C_3N_4$ , NH $_4$ Cl, and NC, is fully decomposed into NH $_3$  and HCl at 295 °C, and the combustion of NC is observed from 250 °C to 520 °C. ³6 Fig. 2c illustrates the improved thermal stability of  $C_3N_4/NC$  over bulk  $C_3N_4$ .

The morphology of as-synthesized bulk  $C_3N_4$ ,  $C_3N_4$ , and  $C_3N_4/NC$  was studied by transmission electron microscopy (TEM). Bulk  $C_3N_4$  shows a dense layer-stacking feature (Fig.-S1a†), while  $C_3N_4$  presents 2D sheets (Fig. 3a). The distinct morphology difference confirms the efficient exfoliation of  $C_3N_4$ . For crystalline  $C_3N_4/NC$ , NC sheets with small pores are attached to the  $C_3N_4$  sheets (Fig. 3b and c), and they obviously increase with the NC mass ratios in photocatalysts (Fig. S1†).

The simultaneous formation of thin C<sub>3</sub>N<sub>4</sub> sheets and numerous pores is attributed to the introduction of the NH<sub>4</sub>Cl gas template. Based on the Brunauer-Emmett-Teller (BET) theory, the specific surface area and the pore volume are fully investigated. As shown in Fig. 3d, the optimized C<sub>3</sub>N<sub>4</sub>/NC has a significantly higher surface area of 65.4 m<sup>2</sup> g<sup>-1</sup> and pore volume of 0.340 cm<sup>3</sup> g<sup>-1</sup> compared to the bulk C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>4</sub> (Fig. S2†). The crystal structures of the as-prepared samples are characterized by X-ray diffraction (XRD), as displayed in Fig. 3e. Two characteristic peaks at 13° and 27° can be well indexed to  $C_3N_4$ , which corresponds to peaks (100) and (002); (100) reflects the in-plane structural packing motif peak, and (002) represents the interplanar stacking of the conjugated aromatic system.<sup>37</sup> The peaks of the (002) plane slightly shifting towards a higher degree is also observed in Fig. 3f, which corresponds to the reduction of the stacking distance after an NH4Cl blowing procedure at high temperature.38

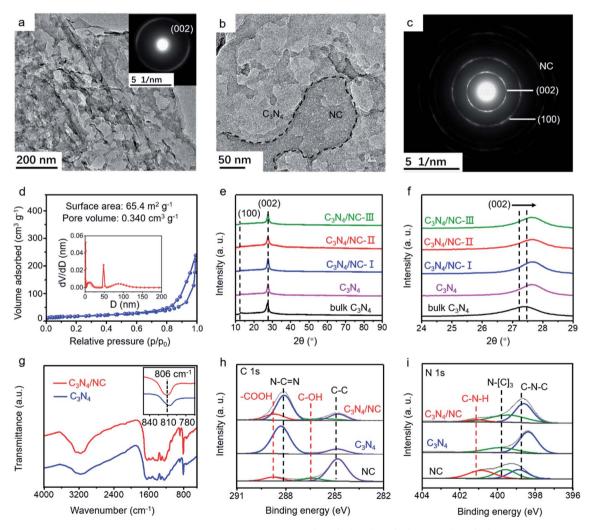


Fig. 3 Characterization of the synthesized samples. In different samples of  $C_3N_4/NC$ -I,  $C_3N_4/NC$ -II, and  $C_3N_4/NC$ -III, the mass ratios of NC were 0.05%, 0.075%, and 0.10%, respectively. The optimal  $C_3N_4/NC$ -II is denoted as  $C_3N_4/NC$  unless otherwise stated. (a) and (b) TEM images of  $C_3N_4$  and  $C_3N_4/NC$ , respectively; (c) SAED images of NC; (d)  $N_2$  adsorption—desorption isotherms and pore size distribution plots of  $C_3N_4/NC$ ; (e) XRD patterns of all samples; (f) enlarged XRD patterns in the range of 24–29°; (g) FTIR spectra of  $C_3N_4$  and  $C_3N_4/NC$  samples, the inset shows the enlarged peaks around 810 cm $^{-1}$ ; (h) and (i)  $C_3N_4/NC$  spectra of NC,  $C_3N_4/NC$ , respectively.

Fourier transform infrared spectroscopy (FTIR) and X-ray photoelectron spectroscopy (XPS) are employed to investigate the local chemical composition and states of  $C_3N_4$  and  $C_3N_4/NC$ . In the FTIR spectra, the peaks located between 1200 and 1700 cm<sup>-1</sup> are ascribed to the CN heterocycle stretching modes (Fig. 3g).<sup>39,40</sup> The broad peaks at 2800–3400 cm<sup>-1</sup> correspond to the O–H and N–H stretching vibrations, which indicates the presence of surface hydroxyl and amino groups.<sup>36,41</sup> The sharp peak at 806 cm<sup>-1</sup> represents the characteristic breathing mode of the tri-s-triazine units.<sup>42</sup> The FTIR profiles of  $C_3N_4$  and  $C_3N_4/NC$  are very similar, suggesting that the introduction of NC barely changes the basic structure of  $C_3N_4$ . However, it should be noted that there is a slight peak shift for  $C_3N_4/NC$  at around 810 cm<sup>-1</sup>, which may result from the interaction between  $C_3N_4$  and  $NC.^{43}$ 

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XPS results of C<sub>3</sub>N<sub>4</sub>/NC, C<sub>3</sub>N<sub>4</sub>, and NC are collected to investigate the specific interaction between C<sub>3</sub>N<sub>4</sub> and NC. For C<sub>3</sub>N<sub>4</sub>, the XPS C 1s spectrum is divided into C-C (284.8 eV) and N-C=N (287.9 eV), and the N 1s spectrum is split into two peaks at 398.4 and 399.9 eV, which are attributed to sp<sup>2</sup>-hybridized nitrogen (C-N=C) and sp<sup>3</sup>-hybridized nitrogen (N-[C]<sub>3</sub>), respectively (Fig. 3h and i).43-47 A noticeable new peak at 289.3 eV is observed for C<sub>3</sub>N<sub>4</sub>/NC, which originates from -COOH of NC. Notably, the peak shift of N-C=N towards higher binding energy in  $C_3N_4/NC$  results from the  $\pi$ - $\pi$  stacking interaction between C<sub>3</sub>N<sub>4</sub> and NC.<sup>48,49</sup> The percentages of various atomic bonds are listed in Table S1,† based on the C 1s and N 1s spectra of C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>4</sub>/NC. The increased atomic percentages of N-C=N, -COOH, C-N-H, and N-(C)<sub>3</sub> in C<sub>3</sub>N<sub>4</sub>/ NC are attributed to the introduction of NC. This noncovalent interaction significantly contributes to the 2D-2D contact at the interface between C<sub>3</sub>N<sub>4</sub> and NC, which is beneficial to the enhanced charge separation and transfer of C<sub>3</sub>N<sub>4</sub>/NC photocatalysts.

To determine the direct Z-scheme heterojunction, the bandgap  $(E_g)$  and valence band (VB) information of  $C_3N_4$  and NC are gathered. As shown in Fig. 4a, there is an intrinsic absorption edge at around 420 nm for C<sub>3</sub>N<sub>4</sub>, and the related band gap is estimated to be 3.02 eV. NC exhibits a broad absorption in the UV-vis region, and the estimated bandgap is 2.34 eV (Fig. 4b). In Fig. 4c, the VBs of C<sub>3</sub>N<sub>4</sub> and NC are confirmed to be 1.42 and 3.11 eV through the valence band Xray photoelectron spectroscopy (VB-XPS). Then, CB positions of  $C_3N_4$  and NC are determined to be -1.60 and 0.77 eV, based on the following equation:  $E_{CB} = E_{VB} - E_{g}$ , where  $E_{CB}$ ,  $E_{VB}$ , and  $E_{g}$  are the conduction band position, valence band position, and bandgap, respectively.  $^{50}$  The CB positions of  $C_3N_4$  and NC are consistent with the experimental results in Fig. S3a and b.† The resulting charge transfer mechanism of C<sub>3</sub>N<sub>4</sub>/NC is plotted in Fig. 4d. According to the staggered band structures of C<sub>3</sub>N<sub>4</sub> and NC, the excited electrons in the CB of NC are paired with the holes in the VB of C<sub>3</sub>N<sub>4</sub>, while the remaining electrons stay in the CB (-1.60 eV). As the CB position of  $C_3N_4$  at -1.60 eV is more negative than the water reduction potential (-0.41 eV), it is thermodynamically favorable for those accumulated electrons in the CB of C<sub>3</sub>N<sub>4</sub> to trigger H<sub>2</sub> evolution. Meanwhile, the holes remain in the VB of NC at 3.11 eV, which is beneficial to

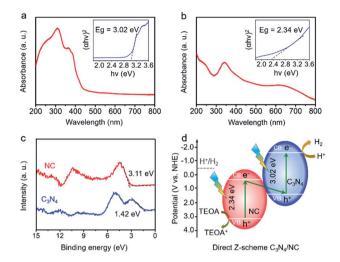


Fig. 4 The direct Z-scheme heterojunction in  $C_3N_4/NC$ . (a) and (b) Light absorption and  $E_g$  spectra (the inset plot) of  $C_3N_4$  and NC, respectively; (c) VB-XPS spectra of  $C_3N_4$  and NC; (d) the charge transfer mechanism of the direct Z-scheme heterojunction in  $C_3N_4/NC$ .

the efficient oxidation reaction. The specific oxidation reaction paths including intermediates are shown in Fig. S4.† Therefore, a direct Z-scheme heterojunction is achieved by pairing  $C_3N_4$  with NC.

The visible-light photocatalytic performance of H<sub>2</sub> production is evaluated by using an online photocatalytic test instrument (Fig. S5†). As presented in Fig. 5a, C<sub>3</sub>N<sub>4</sub> shows a sharp improvement of visible light photocatalytic H2 evolution activity compared with bulk C<sub>3</sub>N<sub>4</sub>. The enhanced H<sub>2</sub> production rate is partially attributed to the larger surface area (from  $6.4 \text{ m}^2 \text{ g}^{-1}$  to  $52.5 \text{ m}^2 \text{ g}^{-1}$ , Fig. 3d and  $S2^{\dagger}$ ) resulting from the formation of 2D porous sheets. Furthermore, the H<sub>2</sub> evolution rate of C<sub>3</sub>N<sub>4</sub> can be boosted by constructing 2D C<sub>3</sub>N<sub>4</sub>/NC with a direct Z-scheme heterojunction through regulating the mass ratio of NC in C<sub>3</sub>N<sub>4</sub>/ NC. As expected, all three C<sub>3</sub>N<sub>4</sub>/NC samples show considerably improved H2 production rate and the optimized C3N4/NC-II exhibits the highest  $H_2$  evolution rate of 3.060 mmol  $h^{-1}$   $g^{-1}$ (Fig. 5a and S6†) and external quantum efficiency (EQE, 6.79% at 400 nm). Such an impressive H<sub>2</sub> production rate in C<sub>3</sub>N<sub>4</sub>/NC is over 46 fold that of bulk C<sub>3</sub>N<sub>4</sub>. On the one hand, the formation of a well-defined 2D-2D structure results in large interfacial contact for charge separation and surface area for photocatalysis. On the other hand, benefiting from the direct Zscheme mechanism (Fig. 4d), charge carriers are spatially separated, and electrons with strong reducing capacity are preserved in the CB of C<sub>3</sub>N<sub>4</sub>, which highly retains the reduction ability of C<sub>3</sub>N<sub>4</sub>/NC to reduce H<sup>+</sup> into H<sub>2</sub>. However, the excessive NC will cover the surface of C<sub>3</sub>N<sub>4</sub> (Fig. S1†), resulting in a decrease in the effective active sites for H<sub>2</sub> production. This is proved through the H<sub>2</sub> evolution rate normalized by the surface area, as shown in Fig. 5a. Hence, C<sub>3</sub>N<sub>4</sub>/NC demonstrates superior photocatalytic activity of H2 production compared with other carbon nitride-based systems in previous reports (Tables S2 and S3†). The stability of the optimized g-C<sub>3</sub>N<sub>4</sub>/NC-II is

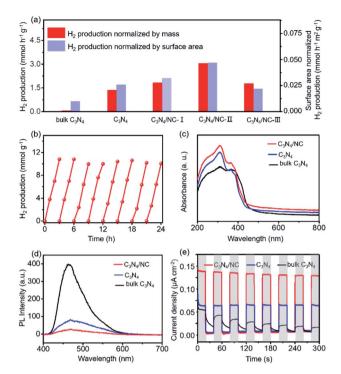


Fig. 5 Photocatalytic performances of H<sub>2</sub> production and the mechanism of enhanced activity. (a) The photocatalytic rate over various samples.  $C_3N_4/NC$ -I,  $C_3N_4/NC$ -II, and  $C_3N_4/NC$ -III were prepared with the NC mass ratios in  $C_3N_4/NC$  of 0.05%, 0.075%, and 0.10%, respectively; (b) cyclic curves of C<sub>3</sub>N<sub>4</sub>/NC-II; (c) UV-vis diffuse reflectance spectra (DRS); (d) PL spectra; (e) chronoamperometry curves under chopped visible-light illumination. The gray background means the light is on, and the white one means the light is off; the photocatalytic reaction occurs under visible light irradiation.

evaluated by recycling it over eight cycles for 24 h (Fig. 5b). Remarkably, the H<sub>2</sub> production remains consistent without deactivation and the XPS spectra slightly change (Fig. S7†) after the whole eight cycles, manifesting its excellent stability.

To reveal the fundamental mechanism behind the significantly enhanced photocatalytic performances of 2D direct Zscheme C<sub>3</sub>N<sub>4</sub>/NC photocatalysts, the optical properties, transient photocurrent response, photoluminescence (PL), and electrochemical impedance spectra (EIS) are comprehensively studied. The UV-vis diffuse reflectance spectra (DRS) show that the ranking of the visible light absorption strength is C<sub>3</sub>N<sub>4</sub>/NC >  $C_3N_4$  > bulk  $C_3N_4$  (Fig. 5c). Furthermore, a higher charge separation rate can be reflected by the lower fluorescence emission intensity through the PL spectroscopy,51,52 where the PL intensity of C<sub>3</sub>N<sub>4</sub>/NC is lower than that of bulk C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>4</sub> (Fig. 5d). The single peak of PL emission at 465 nm is ascribed to the bandgap transition of C<sub>3</sub>N<sub>4</sub>. More importantly, the separation/transfer capability of charge carriers is evaluated through the transient photocurrent response.<sup>53</sup> As displayed in Fig. 5e, C<sub>3</sub>N<sub>4</sub>/NC exhibits a significantly higher photocurrent density than those of bulk C<sub>3</sub>N<sub>4</sub> and C<sub>3</sub>N<sub>4</sub>. To reveal the interfacial charge carrier transfer resistance, EIS is carried out. In Fig. S8,† the EIS spectra of C<sub>3</sub>N<sub>4</sub>/NC and C<sub>3</sub>N<sub>4</sub> are modeled through the equivalent Randle circuit composed of the

interfacial charge transfer resistance at the electrode/electrolyte interface  $(R_{ct})$ , electrolyte solution resistance  $(R_s)$ , and constant phase element (CPE). 54,55 A lower  $R_{\rm ct}$  of 455  $\Omega$  in  $C_3N_4/NC$  is achieved when compared to that of  $C_3N_4$  (576  $\Omega$ ). These characterization results consistently support that the enhanced photocatalytic H<sub>2</sub> evolution activity is mainly ascribed to the improved separation and transfer of charge carriers, which originates from the synthetic merits of the direct Z-scheme heterojunction and the 2D-2D structure of the C<sub>3</sub>N<sub>4</sub>/NC photocatalysts.

In summary, we have synthesized 2D direct Z-scheme C<sub>3</sub>N<sub>4</sub>/ NC photocatalysts by a gas template-assisted thermal condensation method. We demonstrated that the synthesized C<sub>3</sub>N<sub>4</sub>/NC has well-defined 2D-2D interfaces and a direct Z-scheme heterojunction via  $\pi$ - $\pi$  stacking interaction. The direct Z-scheme heterojunction facilitates the charge-hole separation and the retention of redox ability, and large interfacial contact from 2D-2D interaction further promotes the photocatalysis of hydrogen evolution. The highest H<sub>2</sub> evolution rate of C<sub>3</sub>N<sub>4</sub>/NC reaches 3.060 mmol  $h^{-1}$   $g^{-1}$ , which is 46 times higher than that of bulk C<sub>3</sub>N<sub>4</sub>. The enhanced photocatalytic performances are attributed to the improved separation and transfer of charge carriers benefiting from the direct Z-scheme heterojunction and the 2D-2D structure. This work enables the significant improvement of charge carrier separation by integrating 2D materials with direct Z-scheme heterojunctions, which provides a novel material design strategy for heterojunctions.

#### Conflicts of interest

There are no conflicts to declare.

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